


APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	METHOD OF MAKING FIELD EFFECT TRANSISTORS HAVING SELF-ALIGNED SOURCE AND DRAIN REGIONS USING INDEPENDENTLY CONTROLLED SPACER WIDTHS		
Application Type : regular, utility			
Attorney Docket Number : FIS920030358US1			
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Publication Information:			
Suggested Figure for Publication - 1			
Suggested Classification -			
Suggested Technology Center -			
Total Number of Drawing Sheets - 12			

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